

# LMR23610 SIMPLE SWITCHER® 36V、1A同期整流降圧型コンバータ

## 1 特長

- 入力電圧範囲: 4V~36V
- 1Aの連続出力電流
- 同期整流器内蔵
- 電流モード制御
- 最小スイッチオン時間: 60ns
- スwitchング周波数400kHz、PFMモード搭載
- 外部クロックへの周波数同期
- 設計を容易にする内部補償
- 無負荷時の静止電流75 $\mu$ A
- プリバイアス負荷に対応したソフト・スタート
- 高いデューティ・サイクルでの動作をサポート
- 高精度イネーブル入力
- ヒカッパ・モードによる出力短絡保護
- 過熱保護
- 8ピンのHSOIC PowerPAD™パッケージで供給
- WEBENCH® Power Designerにより、LMR23610を使用するカスタム設計を作成

## 2 アプリケーション

- ファクトリ/ビル・オートメーション・システム: PLC CPU、HVAC制御、エレベータ制御
- フリート管理、スマート・グリッド、セキュリティ用GSM/GPRSモジュール
- 汎用の広いVinレギュレーション

## 3 概要

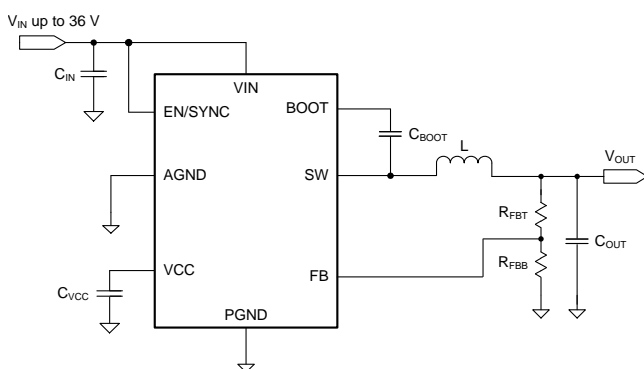
LMR23610 SIMPLE SWITCHER®は、使いやすい36V、1Aの同期整流降圧型レギュレータです。4V~36Vという幅広い入力範囲により、産業用から車載向けまで、非レギュレーション電源からの電源調整を行うさまざまなアプリケーションに適しています。ピーク電流モード制御の採用によって、単純な制御ループ補償とサイクル単位の電流制限を実現しています。静止電流が75 $\mu$ Aであるため、バッテリー駆動のシステムに適しています。シャットダウン電流も2 $\mu$ Aと極めて低いことから、バッテリー駆動時間のさらなる延長が可能です。内部ループ補償により、ユーザーはループ補償を設計する煩雑な作業から解放されます。これによって、外付け部品の数も最小限に抑えられます。拡張ファミリとして、2.5A (LMR23625)および3A (LMR23630)の負荷電流オプションを提供しており、いずれもピン互換パッケージを採用しているため、PCBレイアウトの簡素化と最適化が実現します。高精度のイネーブル入力により、レギュレータの制御とシステムの電源シーケンシングが単純化されます。保護機能として、サイクル単位の電流制限、ヒカッパ・モードの短絡保護、過剰な消費電力によるサーマル・シャットダウンが搭載されています。

### 製品情報<sup>(1)</sup>

型番	パッケージ	本体サイズ(公称)
LMR23610A	HSOIC (8)	4.89mm×3.90mm

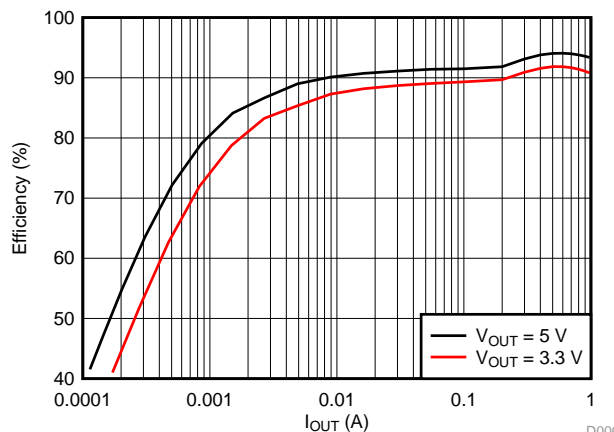
(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

概略回路図



効率と負荷との関係

$V_{IN} = 12V$



D000



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## 4 改訂履歴

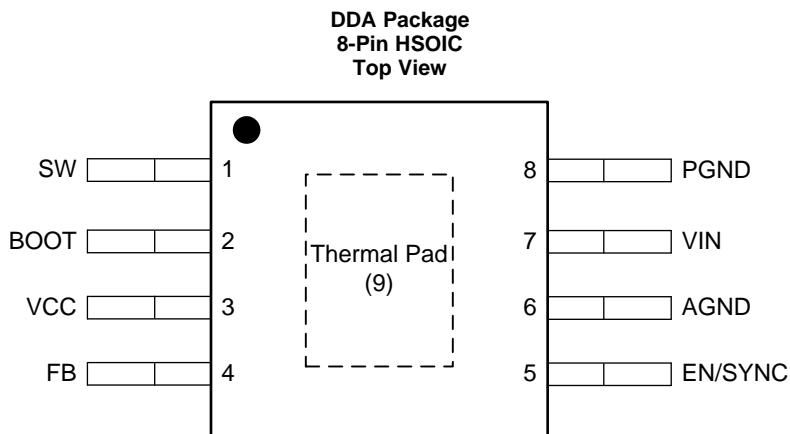
資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision B (April 2017) から Revision C に変更	Page
「車載用バッテリー・レギュレーション」を「アプリケーション」から 削除	1
入力電圧範囲: 「4.5V」を「入力電圧範囲: 4V...」に(「特長」)、「4.5V~...という幅広い入力範囲」を「4V~...という幅広い入力範囲」に(「概要」) 変更	1
Added "2.2- $\mu$ F, 16-V" for VCC pin bypass capacitor	3
Changed ESD HBM value from " $\pm$ 2500" to " $\pm$ 2000"	4
Changed "4.5" in VIN row of Input voltage ROC table to "4"	4
Changed "4.5" to "4" in V <sub>IN</sub> row under POWER SUPPLY	5
Changed "3.4" to "3.3" in VIN_UVLO row under POWER SUPPLY	5
Changed "hysteresis" to "threshold", "0.4" to "3.3" in VIN_UVLO row under POWER SUPPLY; add min = 2.9 and max = 3.5 in same row	5
Changed "V <sub>IN</sub> = 4.5 V to 36 V" in ISHDN row of POWER SUPPLY to "V <sub>IN</sub> = 12 V"	5
Changed "V <sub>IN</sub> = 4.5 V" to "V <sub>IN</sub> = 4 V" in EC Test Conditions column starting with ENABLE (EN PIN)	5
Added "90" to MAX column of T <sub>ON_MIN</sub> time under SW (SW PIN)	6
Changed operating from "4.5-V" to "4-V" in first sentence of <a href="#">Overview</a>	9
Changed "...when the input voltage is in the operating range 4.5 V..." to "...when the input voltage is in the operating range 4 V..." in <a href="#">Active Mode</a>	16
Changed "V <sub>OUT</sub> = 7 V to 36 V..." to "V <sub>IN</sub> = 7 V to 36 V..."	22

Revision A (July 2016) から Revision B に変更	Page
Changed the high side current max limit to 2.6 from 2.5 and low side current max limit to 2.1 from 1.9	5

2015年12月発行のものから更新	Page
残るすべてのセクションを追加し、開発中から量産データに変更	1

## 5 Pin Configuration and Functions



### Pin Functions

PIN		I/O <sup>(1)</sup>	DESCRIPTION
NO.	NAME		
1	SW	O	Switching output of the regulator. Internally connected to both power MOSFETs. Connect to power inductor.
2	BOOT	O	Boot-strap capacitor connection for high-side driver. Connect a high-quality 470-nF capacitor from BOOT to SW.
3	VCC	O	Internal bias supply output for bypassing. Connect a 2.2- $\mu$ F, 16-V bypass capacitor from this pin to AGND. Do not connect external loading to this pin. Never short this pin to ground during operation.
4	FB	I	Feedback input to regulator, connect the feedback resistor divider tap to this pin.
5	EN/SYNC	I	Enable input to regulator. High = On, Low = Off. Can be connected to VIN. Do not float. Adjust the input under voltage lockout with two resistors. The internal oscillator can be synchronized to an external clock by coupling a positive pulse into this pin through a small coupling capacitor. See <a href="#">EN/SYNC</a> for details.
6	AGND	G	Analog ground pin. Ground reference for internal references and logic. Connect to system ground.
7	VIN	I	Input supply voltage.
8	PGND	G	Power ground pin, connected internally to the low side power FET. Connect to system ground, PAD, AGND, ground pins of C <sub>IN</sub> and C <sub>OUT</sub> . Path to C <sub>IN</sub> must be as short as possible.
9	PAD	G	Low impedance connection to AGND. Connect to PGND on PCB. Major heat dissipation path of the die. Must be used for heat sinking to ground plane on PCB.

(1) I = Input, O = Output, G = Ground

## 6 Specifications

### 6.1 Absolute Maximum Ratings

Over the recommended operating junction temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		MIN	MAX	UNIT
Input voltages	VIN to PGND	-0.3	42	V
	EN to AGND	-5.5	$V_{\text{IN}} + 0.3$	
	FB to AGND	-0.3	4.5	
	AGND to PGND	-0.3	0.3	
Output voltages	SW to PGND	-1	$V_{\text{IN}} + 0.3$	V
	SW to PGND less than 10 ns transients	-5	42	
	BOOT to SW	-0.3	5.5	
	VCC to AGND	-0.3	4.5	
T <sub>J</sub>	Junction temperature	-40	150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM) <sup>(1)</sup>	±2000
		Charged-device model (CDM) <sup>(2)</sup>	±1000

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

Over the recommended operating junction temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Input voltage	VIN	4	36	V
	EN	-5	36	
	FB	-0.3	1.2	
Output voltage	V <sub>OUT</sub>	1	28	V
Output current	I <sub>OUT</sub>	0	1	A
Temperature	Operating junction temperature, T <sub>J</sub>	-40	125	°C

(1) Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For specified specifications, see [Electrical Characteristics](#).

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)(2)</sup>		LMR23610	
		DDA (HSOIC)	UNIT
		8 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	42.0	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	5.9	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	23.4	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	45.8	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	3.6	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	23.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.
- (2) Power rating at a specific ambient temperature T<sub>A</sub> should be determined with a maximum junction temperature (T<sub>J</sub>) of 125°C, which is illustrated in [Recommended Operating Conditions](#).

## 6.5 Electrical Characteristics

Limits apply over the recommended operating junction temperature (T<sub>J</sub>) range of –40°C to +125°C, unless otherwise stated. Minimum and Maximum limits are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at T<sub>J</sub> = 25°C, and are provided for reference purposes only.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
<b>POWER SUPPLY (VIN PIN)</b>							
V <sub>IN</sub>	Operation input voltage	4		36	V		
VIN_UVLO	Undervoltage lockout thresholds	Rising threshold	3.3	3.7	3.9	V	
		Falling threshold	2.9	3.3	3.5		
I <sub>SHDN</sub>	Shutdown supply current	V <sub>EN</sub> = 0 V, V <sub>IN</sub> = 12 V, T <sub>J</sub> = –40°C to 125°C		2	4	μA	
I <sub>Q</sub>	Operating quiescent current (non-switching)	V <sub>IN</sub> = 12 V, V <sub>FB</sub> = 1.1 V, T <sub>J</sub> = –40°C to 125°C, PFM mode		75		μA	
<b>ENABLE (EN/SYNC PIN)</b>							
V <sub>EN_H</sub>	Enable rising threshold voltage	1.4	1.55	1.7	V		
V <sub>EN_HYS</sub>	Enable hysteresis voltage		0.4		V		
V <sub>WAKE</sub>	Wake-up threshold	0.4			V		
I <sub>EN</sub>	Input leakage current at EN pin	V <sub>IN</sub> = 4 V to 36 V, V <sub>EN</sub> = 2 V		10	100	nA	
		V <sub>IN</sub> = 4 V to 36 V, V <sub>EN</sub> = 36 V			1	μA	
<b>VOLTAGE REFERENCE (FB PIN)</b>							
V <sub>REF</sub>	Reference voltage	V <sub>IN</sub> = 4 V to 36 V, T <sub>J</sub> = 25°C		0.985	1	1.015	V
		V <sub>IN</sub> = 4 V to 36 V, T <sub>J</sub> = –40°C to 125°C		0.98	1	1.02	
I <sub>LKG_FB</sub>	Input leakage current at FB pin	V <sub>FB</sub> = 1 V		10		nA	
<b>INTERNAL LDO (VCC PIN)</b>							
V <sub>CC</sub>	Internal LDO output voltage		4.1		V		
VCC_UVLO	VCC undervoltage lockout thresholds	Rising threshold		2.8	3.2	3.6	V
		Falling threshold		2.4	2.8	3.2	
<b>CURRENT LIMIT</b>							
I <sub>HS_LIMIT</sub>	Peak inductor current limit	1.4	2	2.6	A		
I <sub>LS_LIMIT</sub>	Valley inductor current limit	1	1.5	2.1	A		
I <sub>L_ZC</sub>	Zero cross-current limit		–0.04		A		
<b>INTEGRATED MOSFETS</b>							
R <sub>DS_ON_HS</sub>	High-side MOSFET ON-resistance	V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 1 A		185		mΩ	
R <sub>DS_ON_LS</sub>	Low-side MOSFET ON-resistance	V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 1 A		105		mΩ	
<b>THERMAL SHUTDOWN</b>							
T <sub>SHDN</sub>	Thermal shutdown threshold	162	170	178	°C		
T <sub>HYS</sub>	Hysteresis		15		°C		

## 6.6 Timing Requirements

Over the recommended operating junction temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  (unless otherwise noted)

		MIN	NOM	MAX	UNIT
<b>HICCUP MODE</b>					
$N_{OC}^{(1)}$	Number of cycles that LS current limit is tripped to enter hiccup mode		64		Cycles
$T_{OC}$	Hiccup retry delay time		5		ms
<b>SOFT START</b>					
$T_{SS}$	Internal soft-start time	The time of internal reference to increase from 0 V to 1 V			ms
		1	2	3	

(1) Specified by design.

## 6.7 Switching Characteristics

Over the recommended operating junction temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
<b>SW (SW PIN)</b>					
$f_{SW}$	Default switching frequency	340	400	460	kHz
$T_{ON\_MIN}$	Minimum turnon time		60	90	ns
$T_{OFF\_MIN}^{(1)}$	Minimum turnoff time		100		ns
<b>SYNC (EN/SYNC PIN)</b>					
$f_{SYNC}$	SYNC frequency range	200		2200	kHz
$V_{SYNC}$	Amplitude of SYNC clock AC signal (measured at SYNC pin)	2.8		5.5	V
$T_{SYNC\_MIN}$	Minimum sync clock ON- and OFF-time		100		ns

(1) Specified by design.

### 6.8 Typical Characteristics

Unless otherwise specified the following conditions apply:  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ ,  $L = 22\text{ }\mu\text{H}$ ,  $C_{OUT} = 47\text{ }\mu\text{F} \times 2$ ,  $T_A = 25^\circ\text{C}$ .

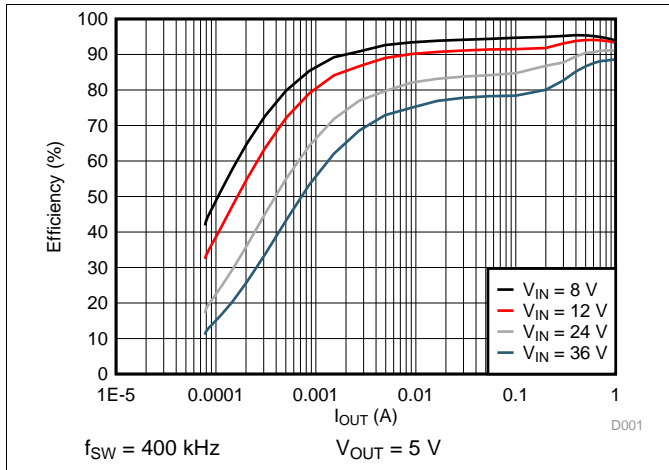


Figure 1. Efficiency vs Load Current

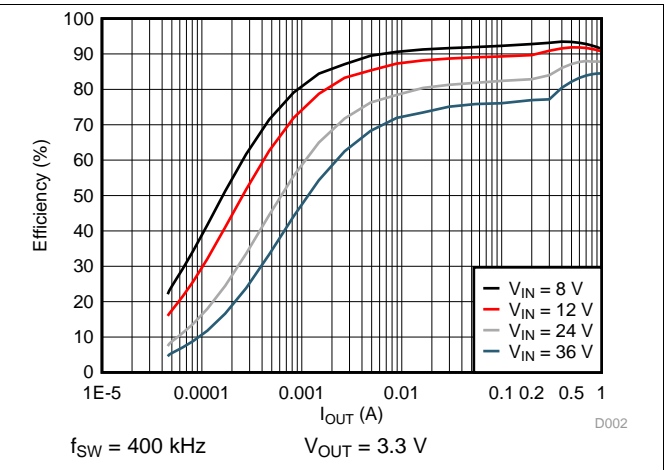


Figure 2. Efficiency vs Load Current

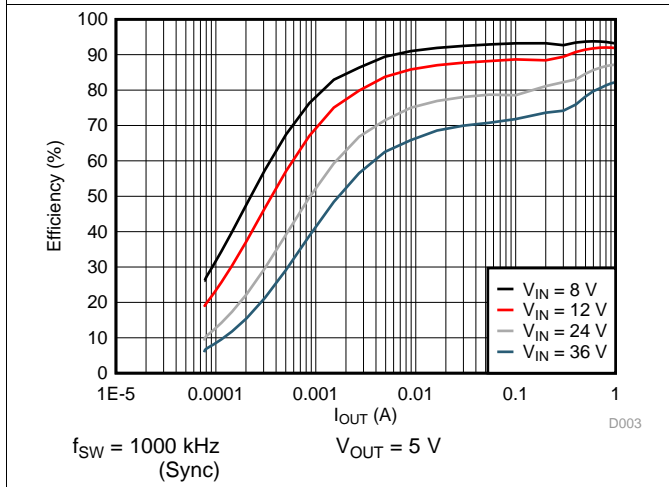


Figure 3. Efficiency vs Load Current

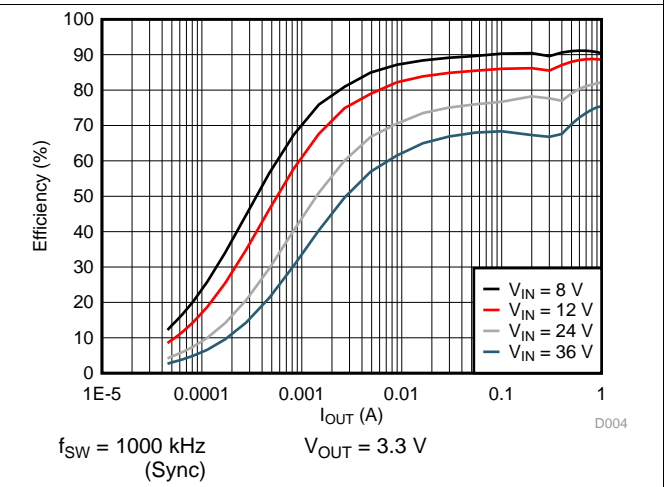


Figure 4. Efficiency vs Load Current

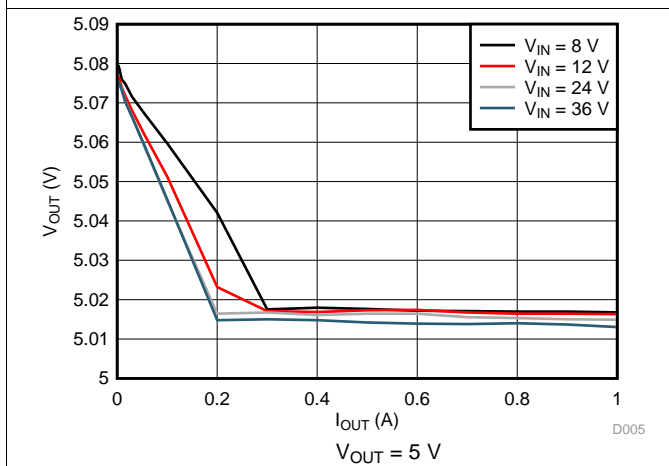


Figure 5. Load Regulation

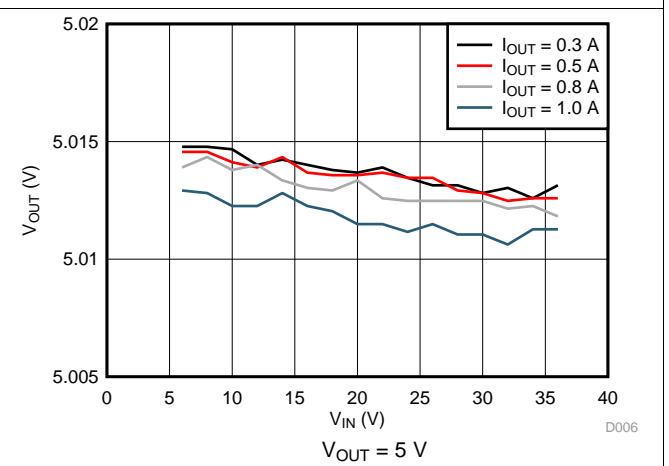
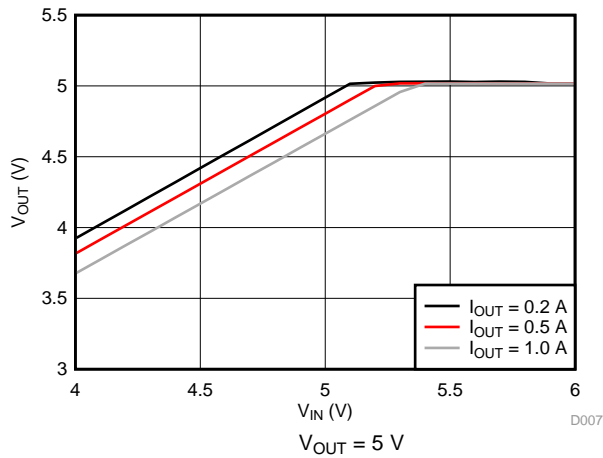


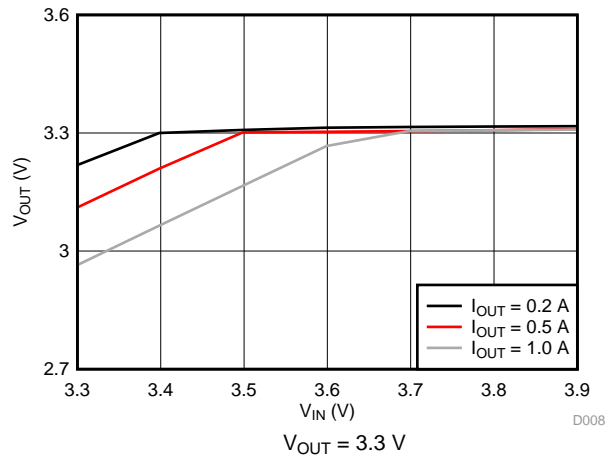
Figure 6. Line Regulation

**Typical Characteristics (continued)**

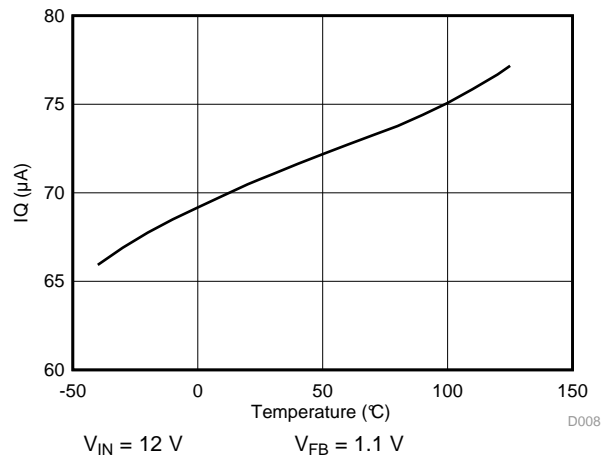
Unless otherwise specified the following conditions apply:  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ ,  $L = 22\text{ }\mu\text{H}$ ,  $C_{OUT} = 47\text{ }\mu\text{F} \times 2$ ,  $T_A = 25^\circ\text{C}$ .



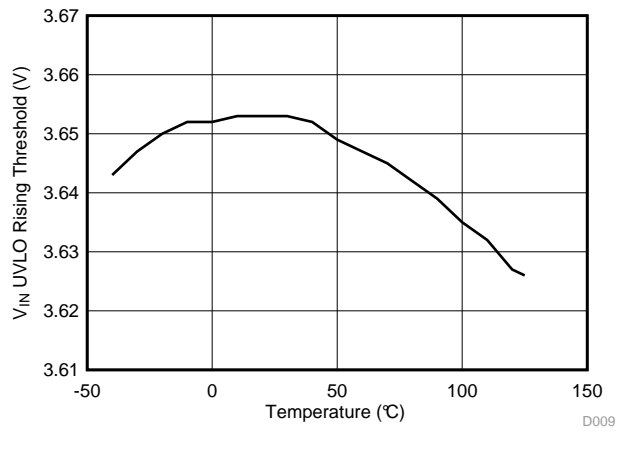
**Figure 7. Dropout Curve**



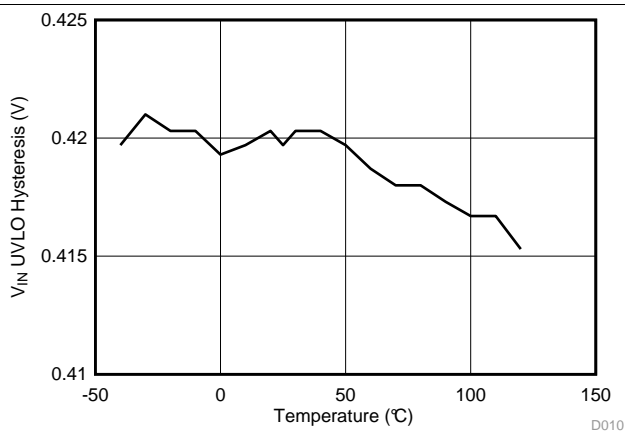
**Figure 8. Dropout Curve**



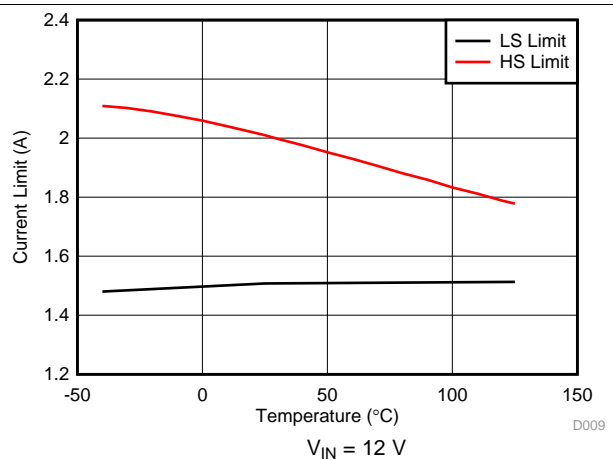
**Figure 9.  $I_Q$  vs Junction Temperature**



**Figure 10.  $V_{IN}$  UVLO Rising Threshold vs Junction Temperature**



**Figure 11.  $V_{IN}$  UVLO Hysteresis vs Junction Temperature**



**Figure 12. HS and LS Current Limit vs Junction Temperature**



## 7 Detailed Description

### 7.1 Overview

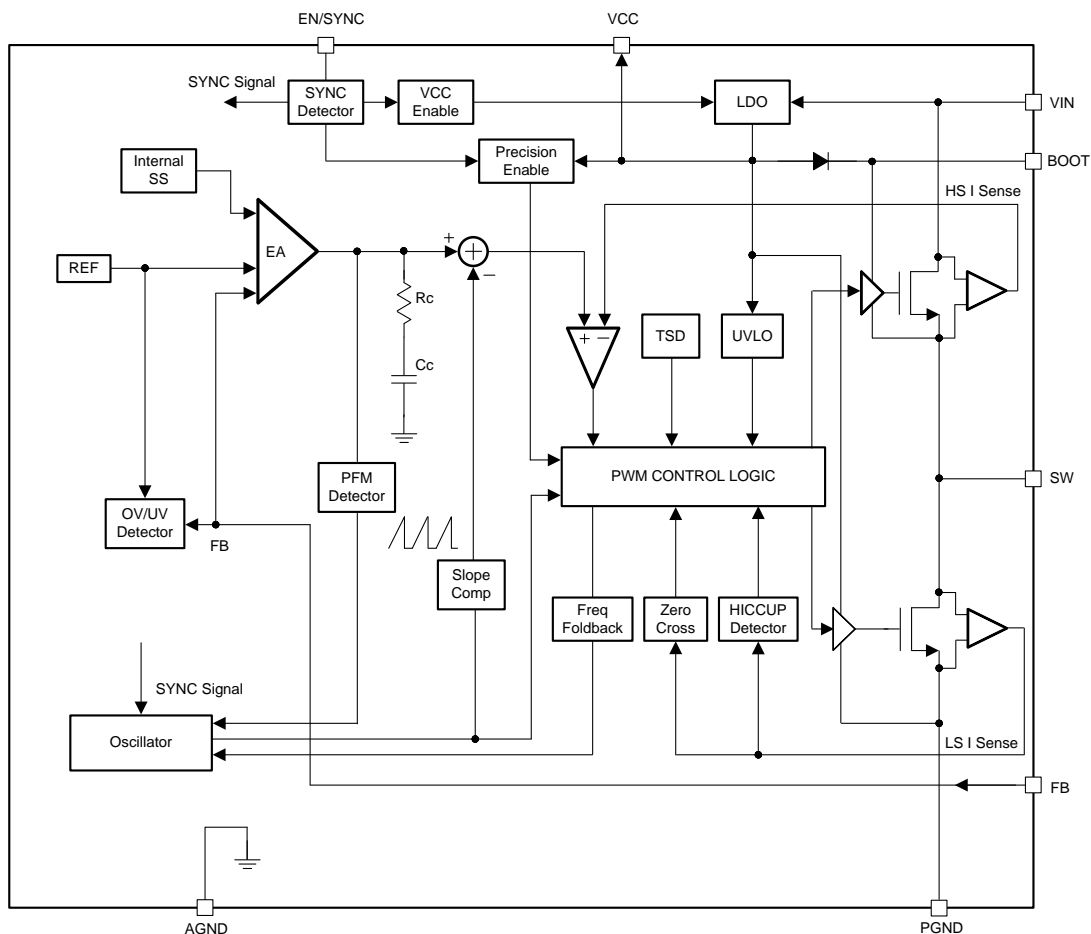
The LMR23610 SIMPLE SWITCHER regulator is an easy-to-use synchronous step-down DC/DC converter operating from 4-V to 36-V supply voltage. It is capable of delivering up to 1-A DC load current with good thermal performance in a small solution size. An extended family is available in multiple current options from 1 A to 3 A in pin-to-pin compatible packages.

The LMR23610 employs fixed-frequency peak-current-mode control. The device enters PFM mode at light load to achieve high efficiency. The device is internally compensated, which reduces design time, and requires few external components. The LMR23610 is capable of synchronization to an external clock within the range of 200 kHz to 2.2 MHz.

Additional features such as precision enable and internal soft-start provide a flexible and easy to use solution for a wide range of applications. Protection features include thermal shutdown, VIN and VCC under-voltage lockout, cycle-by-cycle current limit, and hiccup mode short-circuit protection.

The family requires very few external components and has a pinout designed for simple, optimum PCB layout.

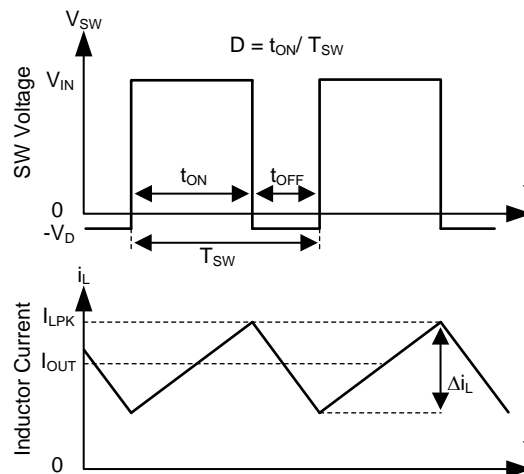
### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Fixed Frequency Peak Current Mode Control

The following operating description of the LMR23610 refers to the [Functional Block Diagram](#) and to the waveforms in [Figure 13](#). LMR23610 is a step-down synchronous buck regulator with integrated high-side (HS) and low-side (LS) switches (synchronous rectifier). The LMR23610 supplies a regulated output voltage by turning on the HS and LS NMOS switches with controlled duty cycle. During high-side switch ON time, the SW pin voltage swings up to approximately  $V_{IN}$ , and the inductor current  $i_L$  increase with linear slope  $(V_{IN} - V_{OUT}) / L$ . When the HS switch is turned off by the control logic, the LS switch is turned on after an anti-shoot-through dead time. Inductor current discharges through the LS switch with a slope of  $-V_{OUT} / L$ . The control parameter of a buck converter is defined as duty cycle  $D = t_{ON} / T_{SW}$ , where  $t_{ON}$  is the high-side switch ON-time and  $T_{SW}$  is the switching period. The regulator control loop maintains a constant output voltage by adjusting the duty cycle  $D$ . In an ideal buck converter, where losses are ignored,  $D$  is proportional to the output voltage and inversely proportional to the input voltage:  $D = V_{OUT} / V_{IN}$ .



**Figure 13. SW Node and Inductor Current Waveforms in Continuous Conduction Mode (CCM)**

The LMR23610 employs fixed frequency peak current mode control. A voltage feedback loop is used to get accurate DC voltage regulation by adjusting the peak current command based on voltage offset. The peak inductor current is sensed from the high-side switch and compared to the peak current threshold to control the ON time of the high-side switch. The voltage feedback loop is internally compensated, which allows for fewer external components, makes it easy to design, and provides stable operation with almost any combination of output capacitors. The regulator operates with fixed switching frequency at normal load condition. At light load condition, the LMR23610 will operate in PFM mode to maintain high efficiency.

### 7.3.2 Adjustable Output Voltage

A precision 1-V reference voltage is used to maintain a tightly regulated output voltage over the entire operating temperature range. The output voltage is set by a resistor divider from output voltage to the FB pin. It is recommended to use 1% tolerance resistors with a low temperature coefficient for the FB divider. Select the low-side resistor  $R_{FBB}$  for the desired divider current and use [Equation 1](#) to calculate high-side  $R_{FBT}$ .  $R_{FBT}$  in the range from 10 k $\Omega$  to 100 k $\Omega$  is recommended for most applications. A lower  $R_{FBT}$  value can be used if static loading is desired to reduce  $V_{OUT}$  offset in PFM operation. Lower  $R_{FBT}$  will reduce efficiency at very light load. Less static current goes through a larger  $R_{FBT}$  and might be more desirable when light load efficiency is critical. But  $R_{FBT}$  larger than 1 M $\Omega$  is not recommended because it makes the feedback path more susceptible to noise. Larger  $R_{FBT}$  value requires more carefully designed feedback path on the PCB. The tolerance and temperature variation of the resistor dividers affect the output voltage regulation.

## Feature Description (continued)

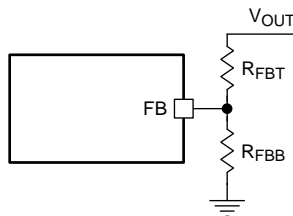


Figure 14. Output Voltage Setting

$$R_{FBT} = \frac{V_{OUT} - V_{REF}}{V_{REF}} \times R_{FBB} \quad (1)$$

### 7.3.3 EN/SYNC

The voltage on the EN pin controls the ON or OFF operation of LMR23610. A voltage less than 1 V (typical) shuts down the device while a voltage higher than 1.6 V (typical) is required to start the regulator. The EN pin is an input and can not be left open or floating. The simplest way to enable the operation of the LMR23610 is to connect the EN to  $V_{IN}$ . This allows self-start-up of the LMR23610 when  $V_{IN}$  is within the operation range.

Many applications will benefit from the employment of an enable divider  $R_{ENT}$  and  $R_{ENB}$  (Figure 15) to establish a precision system UVLO level for the converter. System UVLO can be used for supplies operating from utility power as well as battery power. It can be used for sequencing, ensuring reliable operation, or supply protection, such as a battery discharge level. An external logic signal can also be used to drive EN input for system sequencing and protection.

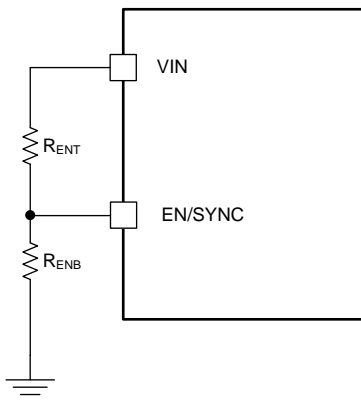
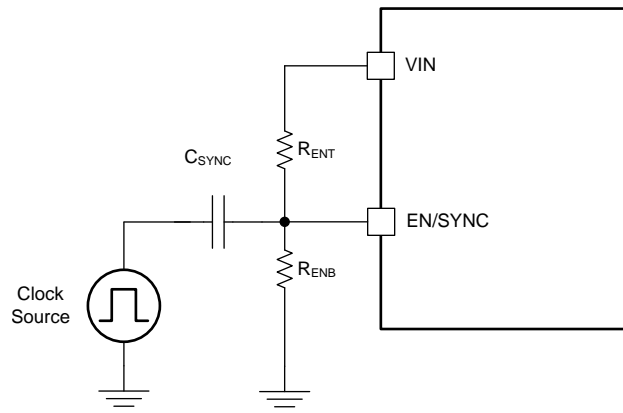
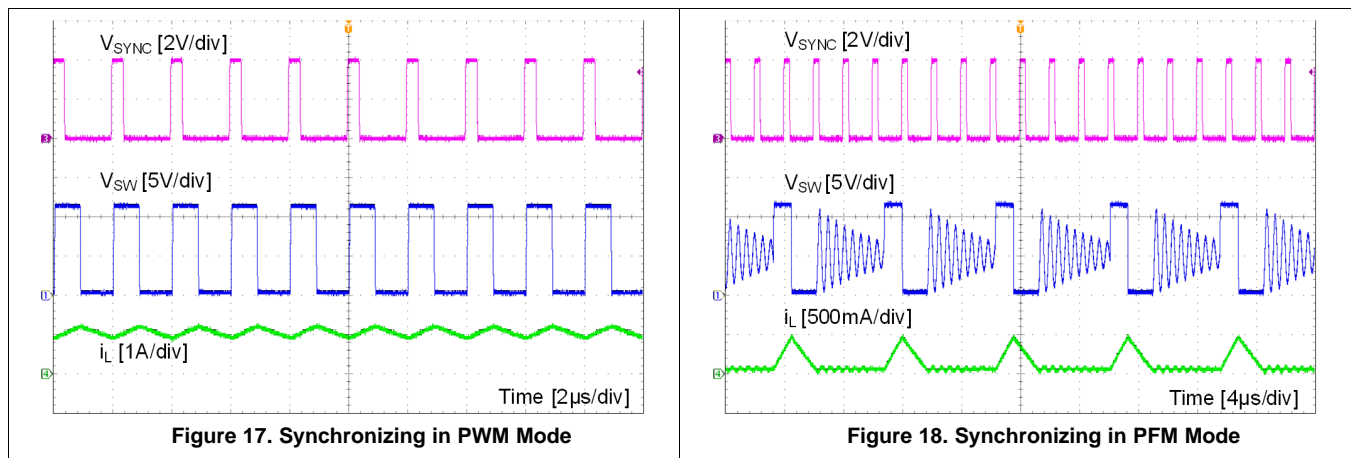


Figure 15. System UVLO by Enable Divider

The EN pin also can be used to synchronize the internal oscillator to an external clock. The internal oscillator can be synchronized by AC coupling a positive edge into the EN pin. The AC coupled peak-to-peak voltage at the EN pin must exceed the SYNC amplitude threshold of 2.8 V (typical) to trip the internal synchronization pulse detector, and the minimum SYNC clock ON and OFF time must be longer than 100ns (typical). A 3.3 V or a higher amplitude pulse signal coupled through a 1 nF capacitor  $C_{SYNC}$  is a good starting point. Keeping  $R_{ENT} // R_{ENB}$  ( $R_{ENT}$  parallel with  $R_{ENB}$ ) in the 100 k $\Omega$  range is a good choice.  $R_{ENT}$  is required for this synchronization circuit, but  $R_{ENB}$  can be left unmounted if system UVLO is not needed. LMR23610 switching action can be synchronized to an external clock from 200 kHz to 2.2 MHz. Figure 17 and Figure 18 show the device synchronized to an external system clock.

**Feature Description (continued)**

**Figure 16. Synchronize to external clock**

**Figure 17. Synchronizing in PWM Mode**
**Figure 18. Synchronizing in PFM Mode**
**7.3.4 V<sub>CC</sub>, UVLO**

The LMR23610 integrates an internal LDO to generate  $V_{CC}$  for control circuitry and MOSFET drivers. The nominal voltage for  $V_{CC}$  is 4.1 V. The  $V_{CC}$  pin is the output of an LDO and must be properly bypassed. A high-quality ceramic capacitor with a value of 2.2  $\mu\text{F}$  to 10  $\mu\text{F}$ , 16 V or higher rated voltage should be placed as close as possible to  $V_{CC}$  and grounded to the exposed PAD and ground pins. The  $V_{CC}$  output pin should not be loaded, or shorted to ground during operation. Shorting  $V_{CC}$  to ground during operation may cause damage to the LMR23610.

$V_{CC}$  undervoltage lockout (UVLO) prevents the LMR23610 from operating until the  $V_{CC}$  voltage exceeds 3.3 V (typical). The  $V_{CC}$  UVLO threshold has 400 mV (typical) of hysteresis to prevent undesired shutdown due to temporary  $V_{IN}$  drops.

**7.3.5 Minimum ON-Time, Minimum OFF-Time and Frequency Foldback at Dropout Conditions**

Minimum ON-time,  $T_{ON\_MIN}$ , is the smallest duration of time that the HS switch can be on.  $T_{ON\_MIN}$  is typically 60 ns in the LMR23610. Minimum OFF-time,  $T_{OFF\_MIN}$ , is the smallest duration that the HS switch can be off.  $T_{OFF\_MIN}$  is typically 100 ns in the LMR23610. In CCM operation,  $T_{ON\_MIN}$  and  $T_{OFF\_MIN}$  limit the voltage conversion range given a selected switching frequency.

The minimum duty cycle allowed is:

$$D_{MIN} = T_{ON\_MIN} \times f_{SW} \quad (2)$$

And the maximum duty cycle allowed is:

$$D_{MAX} = 1 - T_{OFF\_MIN} \times f_{SW} \quad (3)$$

**Feature Description (continued)**

Given fixed  $T_{ON\_MIN}$  and  $T_{OFF\_MIN}$ , the higher the switching frequency the narrower the range of the allowed duty cycle. In the LMR23610, a frequency foldback scheme is employed to extend the maximum duty cycle when  $T_{OFF\_MIN}$  is reached. The switching frequency will decrease once longer duty cycle is needed under low  $V_{IN}$  conditions. Wide range of frequency foldback allows the LMR23610 output voltage stay in regulation with a much lower supply voltage  $V_{IN}$ . This leads to a lower effective drop-out voltage.

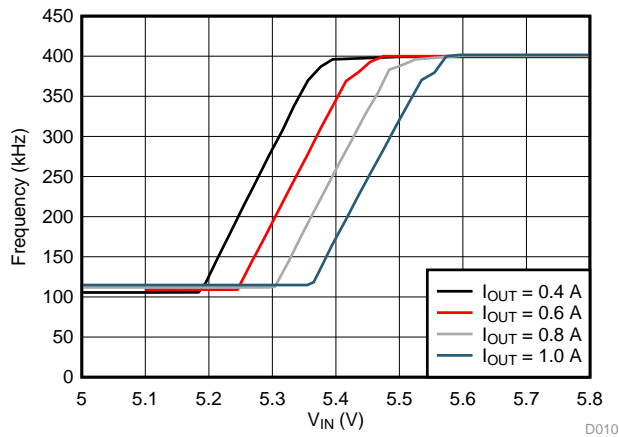
Given an output voltage, the choice of the switching frequency affects the allowed input voltage range, solution size and efficiency. The maximum operation supply voltage can be found by:

$$V_{IN\_MAX} = \frac{V_{OUT}}{(f_{SW} \times T_{ON\_MIN})} \tag{4}$$

At lower supply voltage, the switching frequency will decrease once  $T_{OFF\_MIN}$  is tripped. The minimum  $V_{IN}$  without frequency foldback can be approximated by:

$$V_{IN\_MIN} = \frac{V_{OUT}}{(1 - f_{SW} \times T_{OFF\_MIN})} \tag{5}$$

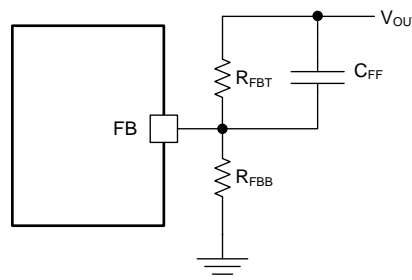
Taking considerations of power losses in the system with heavy load operation,  $V_{IN\_MAX}$  is higher than the result calculated in Equation 4. With frequency foldback,  $V_{IN\_MIN}$  is lowered by decreased  $f_{SW}$ .



**Figure 19. Frequency Foldback at Dropout ( $V_{OUT} = 5\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ )**

**7.3.6 Internal Compensation and  $C_{FF}$**

The LMR23610 is internally compensated as shown in *Functional Block Diagram*. The internal compensation is designed such that the loop response is stable over the entire operating frequency and output voltage range. Depending on the output voltage, the compensation loop phase margin can be low with all ceramic capacitors. An external feed-forward capacitor  $C_{FF}$  is recommended to be placed in parallel with the top resistor divider  $R_{FBT}$  for optimum transient performance.



**Figure 20. Feedforward Capacitor for Loop Compensation**

## Feature Description (continued)

The feed-forward capacitor  $C_{FF}$  in parallel with  $R_{FBT}$  places an additional zero before the cross over frequency of the control loop to boost phase margin. The zero frequency can be found by

$$f_{z\_CFF} = \frac{1}{(2\pi \times C_{FF} \times R_{FBT})} \quad (6)$$

An additional pole is also introduced with  $C_{FF}$  at the frequency of

$$f_{p\_CFF} = \frac{1}{(2\pi \times C_{FF} \times R_{FBT} // R_{FBB})} \quad (7)$$

The zero  $f_{z\_CFF}$  adds phase boost at the crossover frequency and improves transient response. The pole  $f_{p\_CFF}$  helps maintaining proper gain margin at frequency beyond the crossover. [Table 1](#) lists the combination of  $C_{OUT}$ ,  $C_{FF}$  and  $R_{FBT}$  for typical applications, designs with similar  $C_{OUT}$  but  $R_{FBT}$  other than recommended value, please adjust  $C_{FF}$  such that  $(C_{FF} \times R_{FBT})$  is unchanged and adjust  $R_{FBB}$  such that  $(R_{FBT} / R_{FBB})$  is unchanged.

Designs with different combinations of output capacitors need different  $C_{FF}$ . Different types of capacitors have different Equivalent Series Resistance (ESR). Ceramic capacitors have the smallest ESR and need the most  $C_{FF}$ . Electrolytic capacitors have much larger ESR and the ESR zero frequency

$$f_{z\_ESR} = \frac{1}{(2\pi \times C_{OUT} \times ESR)} \quad (8)$$

would be low enough to boost the phase up around the crossover frequency. Designs using mostly electrolytic capacitors at the output may not need any  $C_{FF}$ .

The  $C_{FF}$  creates a time constant with  $R_{FBT}$  that couples in the attenuate output voltage ripple to the FB node. If the  $C_{FF}$  value is too large, it can couple too much ripple to the FB and affect  $V_{OUT}$  regulation. Therefore,  $C_{FF}$  should be calculated based on output capacitors used in the system. At cold temperatures, the value of  $C_{FF}$  might change based on the tolerance of the chosen component. This may reduce its impedance and ease noise coupling on the FB node. To avoid this, more capacitance can be added to the output or the value of  $C_{FF}$  can be reduced.

### 7.3.7 Bootstrap Voltage (BOOT)

The LMR23610 provides an integrated bootstrap voltage regulator. A small capacitor between the BOOT and SW pins provides the gate drive voltage for the high-side MOSFET. The BOOT capacitor is refreshed when the high-side MOSFET is off and the low-side switch conducts. The recommended value of the BOOT capacitor is 0.1  $\mu$ F to 0.47  $\mu$ F. A ceramic capacitor with an X7R or X5R grade dielectric with a voltage rating of 16 V or higher is recommended for stable performance over temperature and voltage.

### 7.3.8 Overcurrent and Short-Circuit Protection

The LMR23610 is protected from overcurrent conditions by cycle-by-cycle current limit on both the peak and valley of the inductor current. Hiccup mode is activated if a fault condition persists to prevent over-heating.

High-side MOSFET overcurrent protection is implemented by the nature of the peak-current-mode control. The HS switch current is sensed when the HS is turned on after a set blanking time. The HS switch current is compared to the output of the error amplifier (EA) minus slope compensation every switching cycle. See [Functional Block Diagram](#) for more details. The peak current of HS switch is limited by a clamped maximum peak current threshold  $I_{HS\_LIMIT}$  which is constant. So the peak current limit of the high-side switch is not affected by the slope compensation and remains constant over the full duty cycle range.

The current going through LS MOSFET is also sensed and monitored. When the LS switch turns on, the inductor current begins to ramp down. The LS switch will not be turned OFF at the end of a switching cycle if its current is above the LS current limit  $I_{LS\_LIMIT}$ . The LS switch will be kept ON so that inductor current keeps ramping down, until the inductor current ramps below the LS current limit  $I_{LS\_LIMIT}$ . Then the LS switch will be turned OFF and the HS switch will be turned on after a dead time. This is somewhat different than the more typical peak current limit, and results in [Equation 9](#) for the maximum load current.

$$I_{OUT\_MAX} = I_{LS\_LIMIT} + \frac{(V_{IN} - V_{OUT})}{2 \times f_{SW} \times L} \times \frac{V_{OUT}}{V_{IN}} \quad (9)$$

## **Feature Description (continued)**

If the current of the LS switch is higher than the LS current limit for 64 consecutive cycles, hiccup current protection mode will be activated. In hiccup mode, the regulator will be shut down and kept off for 5 ms typically before the LMR23610 tries to start again. If over-current or short-circuit fault condition still exist, hiccup will repeat until the fault condition is removed. Hiccup mode reduces power dissipation under severe over-current conditions, prevents over-heating and potential damage to the device.

### **7.3.9 Thermal Shutdown**

The LMR23610 provides an internal thermal shutdown to protect the device when the junction temperature exceeds 170°C (typical). The device is turned off when thermal shutdown activates. Once the die temperature falls below 155°C (typical), the device reinitiates the power up sequence controlled by the internal soft-start circuitry.

## 7.4 Device Functional Modes

### 7.4.1 Shutdown Mode

The EN pin provides electrical ON and OFF control for the LMR23610. When  $V_{EN}$  is below 1 V (typical), the device is in shutdown mode. The LMR23610 also employs  $V_{IN}$  and  $V_{CC}$  UVLO protection. If  $V_{IN}$  or  $V_{CC}$  voltage is below their respective UVLO level, the regulator is turned off.

### 7.4.2 Active Mode

The LMR23610 is in active mode when  $V_{EN}$  is above the precision enable threshold,  $V_{IN}$  and  $V_{CC}$  are above their respective UVLO level. The simplest way to enable the LMR23610 is to connect the EN pin to  $V_{IN}$  pin. This allows self start-up when the input voltage is in the operating range 4 V to 36 V. See [VCC, UVLO and EN/SYNC](#) for details on setting these operating levels.

In active mode, depending on the load current, the LMR23610 is in one of three modes:

1. Continuous conduction mode (CCM) with fixed switching frequency when load current is above half of the peak-to-peak inductor current ripple.
2. Discontinuous conduction mode (DCM) with fixed switching frequency when load current is lower than half of the peak-to-peak inductor current ripple in CCM operation.
3. Pulse frequency modulation mode (PFM) when switching frequency is decreased at very light load.

### 7.4.3 CCM Mode

CCM operation is employed in the LMR23610 when the load current is higher than half of the peak-to-peak inductor current. In CCM operation, the frequency of operation is fixed, output voltage ripple is at a minimum in this mode and the maximum output current of 1 A can be supplied by the LMR23610.

### 7.4.4 Light Load Operation

When the load current is lower than half of the peak-to-peak inductor current in CCM, the LMR23610 operates in discontinuous conduction mode (DCM), also known as diode emulation mode (DEM). In DCM, the LS switch is turned off when the inductor current drops to  $I_{L\_ZC}$  (–40 mA typical). Both switching losses and conduction losses are reduced in DCM, compared to forced-PWM operation at light load.

At even lighter current loads, PFM is activated to maintain high efficiency operation. When either the minimum HS switch ON time ( $t_{ON\_MIN}$ ) or the minimum peak inductor current  $I_{PEAK\_MIN}$  (300 mA typ) is reached, the switching frequency decreases to maintain regulation. In PFM, switching frequency is decreased by the control loop when load current reduces to maintain output voltage regulation. Switching loss is further reduced in PFM operation due to less frequent switching actions. The external clock synchronizing will not be valid when LMR23610 enters into PFM mode.



## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The LMR23610 is a step down DC-to-DC regulator. It is typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of 1 A. The following design procedure can be used to select components for the LMR23610. Alternately, the WEBENCH® software may be used to generate complete designs. When generating a design, the WEBENCH® software utilizes iterative design procedure and accesses comprehensive databases of components. See [Custom Design With WEBENCH® Tools](#) and ti.com for more details.

### 8.2 Typical Applications

The LMR23610 only requires a few external components to convert from a wide voltage range supply to a fixed output voltage. [Figure 21](#) shows a basic schematic.

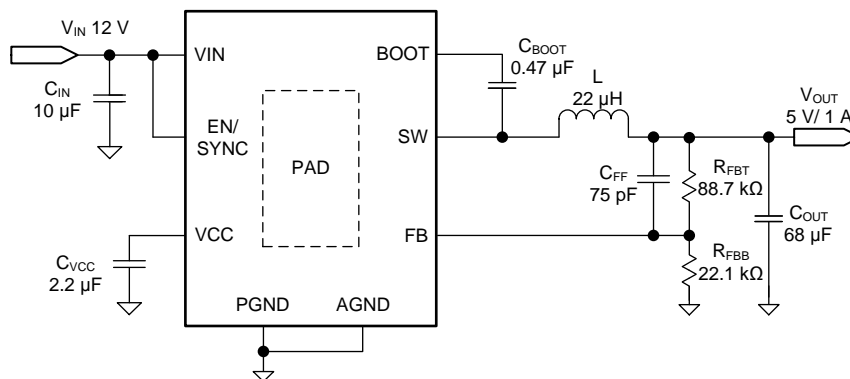


Figure 21. Application Circuit

The external components have to fulfill the needs of the application, but also the stability criteria of the device's control loop. [Table 1](#) can be used to simplify the output filter component selection.

Table 1. L, C<sub>OUT</sub> and C<sub>FF</sub> Typical Values

f <sub>sw</sub> (kHz)	V <sub>OUT</sub> (V)	L (µH) <sup>(1)</sup>	C <sub>OUT</sub> (µF) <sup>(2)</sup>	C <sub>FF</sub> (pF)	R <sub>FBT</sub> (kΩ) <sup>(3)</sup>
400	3.3	15	82	100	51
400	5	22	68	75	88.7
400	12	47	33	See <sup>(4)</sup>	243
400	24	47	22	See <sup>(4)</sup>	510

- (1) Inductance value is calculated based on V<sub>IN</sub> = 36 V.
- (2) All the C<sub>OUT</sub> values are after derating. Add more when using ceramic capacitors.
- (3) R<sub>FBT</sub> = 0 Ω for V<sub>OUT</sub> = 1 V. R<sub>FBB</sub> = 22.1 kΩ for all other V<sub>OUT</sub> settings.
- (4) High ESR C<sub>OUT</sub> gives enough phase boost and C<sub>FF</sub> not needed.

## 8.2.1 Design Requirements

Detailed design procedure is described based on a design example. For this design example, use the parameters listed in [Table 2](#) as the input parameters.

**Table 2. Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage, $V_{IN}$	12 V typical, range from 8 V to 28 V
Output voltage, $V_{OUT}$	5 V
Maximum output current $I_{O\_MAX}$	1 A
Transient response 0.1 A to 1 A	5%
Output voltage ripple	50 mV
Input voltage ripple	400 mV
Switching Frequency $f_{SW}$	400 kHz

## 8.2.2 Detailed Design Procedure

### 8.2.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the LMR23610 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WBENCH](http://www.ti.com/WBENCH).

### 8.2.2.2 Output Voltage Setpoint

The output voltage of LMR23610 is externally adjustable using a resistor divider network. The divider network is comprised of top feedback resistor  $R_{FBT}$  and bottom feedback resistor  $R_{FBB}$ . [Equation 10](#) is used to determine the output voltage:

$$R_{FBT} = \frac{V_{OUT} - V_{REF}}{V_{REF}} \times R_{FBB} \quad (10)$$

Choose the value of  $R_{FBB}$  to be 22.1 kΩ. With the desired output voltage set to 5 V and the  $V_{REF} = 1$  V, the  $R_{FBB}$  value can then be calculated using [Equation 10](#). The formula yields to a value 88.7 kΩ.

### 8.2.2.3 Switching Frequency

The default switching frequency of the LMR23610 is 400 kHz. For other switching frequency, the device must be synchronized to an external clock, please refer to [EN/SYNC](#) for more details.

### 8.2.2.4 Inductor Selection

The most critical parameters for the inductor are the inductance, saturation current and the rated current. The inductance is based on the desired peak-to-peak ripple current  $\Delta i_L$ . Since the ripple current increases with the input voltage, the maximum input voltage is always used to calculate the minimum inductance  $L_{MIN}$ . Use Equation 12 to calculate the minimum value of the output inductor.  $K_{IND}$  is a coefficient that represents the amount of inductor ripple current relative to the maximum output current of the device. A reasonable value of  $K_{IND}$  should be 30% to 50%. During an instantaneous short or over current operation event, the RMS and peak inductor current can be high. The inductor current rating should be higher than the current limit of the device.

$$\Delta i_L = \frac{V_{OUT} \times (V_{IN\_MAX} - V_{OUT})}{V_{IN\_MAX} \times L \times f_{SW}} \quad (11)$$

$$L_{MIN} = \frac{V_{IN\_MAX} - V_{OUT}}{I_{OUT} \times K_{IND}} \times \frac{V_{OUT}}{V_{IN\_MAX} \times f_{SW}} \quad (12)$$

In general, it is preferable to choose lower inductance in switching power supplies, because it usually corresponds to faster transient response, smaller DCR, and reduced size for more compact designs. But too low of an inductance can generate too large of an inductor current ripple such that over current protection at the full load could be falsely triggered. It also generates more conduction loss and inductor core loss. Larger inductor current ripple also implies larger output voltage ripple with same output capacitors. With peak current mode control, it is not recommended to have too small of an inductor current ripple. A larger peak current ripple improves the comparator signal to noise ratio.

For this design example, choose  $K_{IND} = 0.5$ , the minimum inductor value is calculated to be 20.5  $\mu\text{H}$ . Choose the nearest standard 22  $\mu\text{H}$  ferrite inductor with a capability of 2-A RMS current and 2.5-A saturation current.

### 8.2.2.5 Output Capacitor Selection

Choose the output capacitor(s),  $C_{OUT}$ , with care because it directly affects the steady-state output voltage ripple, loop stability and the voltage over/undershoot during load current transients.

The output ripple is essentially composed of two parts. One is caused by the inductor current ripple going through the equivalent series resistance (ESR) of the output capacitors:

$$\Delta V_{OUT\_ESR} = \Delta i_L \times ESR = K_{IND} \times I_{OUT} \times ESR \quad (13)$$

The other is caused by the inductor current ripple charging and discharging the output capacitors:

$$\Delta V_{OUT\_C} = \frac{\Delta i_L}{(8 \times f_{SW} \times C_{OUT})} = \frac{K_{IND} \times I_{OUT}}{(8 \times f_{SW} \times C_{OUT})} \quad (14)$$

The two components in the voltage ripple are not in phase, so the actual peak-to-peak ripple is smaller than the sum of two peaks.

Output capacitance is usually limited by transient performance specifications if the system requires tight voltage regulation with presence of large current steps and fast slew rate. When a fast large load increase happens, output capacitors provide the required charge before the inductor current can slew up to the appropriate level. The regulator's control loop usually needs six or more clock cycles to respond to the output voltage droop. The output capacitance must be large enough to supply the current difference for six clock cycles to maintain the output voltage within the specified range. Equation 15 shows the minimum output capacitance needed for specified output undershoot. When a sudden large load decrease happens, the output capacitors absorb energy stored in the inductor, which results in an output voltage overshoot. Equation 16 calculates the minimum capacitance required to keep the voltage overshoot within a specified range.

$$C_{OUT} > \frac{6 \times (I_{OH} - I_{OL})}{f_{SW} \times V_{US}} \quad (15)$$

$$C_{OUT} > \frac{I_{OH}^2 - I_{OL}^2}{(V_{OUT} + V_{OS})^2 - V_{OUT}^2} \times L$$

where

- $K_{IND}$  = Ripple ratio of the inductor ripple current ( $\Delta i_L / I_{OUT}$ )

- $I_{OL}$  = Low level output current during load transient
  - $I_{OH}$  = High level output current during load transient
  - $V_{US}$  = Target output voltage undershoot
  - $V_{OS}$  = Target output voltage overshoot
- (16)

For this design example, the target output ripple is 50 mV. Presuppose  $\Delta V_{OUT\_ESR} = \Delta V_{OUT\_C} = 50$  mV, and chose  $K_{IND} = 0.5$ . Equation 13 yields ESR no larger than 100 m $\Omega$  and Equation 14 yields  $C_{OUT}$  no smaller than 3.1  $\mu$ F. For the target over/undershoot range of this design,  $V_{US} = V_{OS} = 5\% \times V_{OUT} = 250$  mV. The  $C_{OUT}$  can be calculated to be no smaller than 54  $\mu$ F and 8.5  $\mu$ F by Equation 15 and Equation 16 respectively. Consider of derating, one 82  $\mu$ F, 16 V ceramic capacitor with 5 m $\Omega$  ESR is used.

### 8.2.2.6 Feed-Forward Capacitor

The LMR23610 is internally compensated. Depending on the  $V_{OUT}$  and frequency  $f_{SW}$ , if the output capacitor  $C_{OUT}$  is dominated by low ESR (ceramic types) capacitors, it could result in low phase margin. To improve the phase boost an external feedforward capacitor  $C_{FF}$  can be added in parallel with  $R_{FBT}$ .  $C_{FF}$  is chosen such that phase margin is boosted at the crossover frequency without  $C_{FF}$ . A simple estimation for the crossover frequency ( $f_X$ ) without  $C_{FF}$  is shown in Equation 17, assuming  $C_{OUT}$  has very small ESR, and  $C_{OUT}$  value is after derating.

$$f_X = \frac{8.32}{V_{OUT} \times C_{OUT}} \quad (17)$$

The following equation for  $C_{FF}$  was tested:

$$C_{FF} = \frac{1}{2\pi \times f_X \times R_{FBT}} \quad (18)$$

For designs with higher ESR,  $C_{FF}$  is not needed when  $C_{OUT}$  has very high ESR and  $C_{FF}$  calculated from Equation 18 should be reduced with medium ESR. Table 1 can be used as a quick starting point.

For the application in this design example, a 75 pF, 50 V, COG capacitor is selected.

### 8.2.2.7 Input Capacitor Selection

The LMR23610 device requires high frequency input decoupling capacitor(s) and a bulk input capacitor, depending on the application. The typical recommended value for the high frequency decoupling capacitor is 4.7  $\mu$ F to 10  $\mu$ F. A high-quality ceramic capacitor type X5R or X7R with sufficiency voltage rating is recommended. To compensate the derating of ceramic capacitors, a voltage rating of twice the maximum input voltage is recommended. Additionally, some bulk capacitance can be required, especially if the LMR23610 circuit is not located within approximately 5 cm from the input voltage source. This capacitor is used to provide damping to the voltage spike due to the lead inductance of the cable or the trace. For this design, two 4.7  $\mu$ F, 50 V, X7R ceramic capacitors are used. A 0.1  $\mu$ F for high-frequency filtering and place it as close as possible to the device pins.

### 8.2.2.8 Bootstrap Capacitor Selection

Every LMR23610 design requires a bootstrap capacitor ( $C_{BOOT}$ ). The recommended capacitor is 0.47  $\mu$ F and rated 16 V or higher. The bootstrap capacitor is located between the SW pin and the BOOT pin. The bootstrap capacitor must be a high-quality ceramic type with an X7R or X5R grade dielectric for temperature stability.

### 8.2.2.9 VCC Capacitor Selection

The VCC pin is the output of an internal LDO for LMR23610. To insure stability of the device, place a minimum of 2.2  $\mu$ F, 16 V, X7R capacitor from this pin to ground.

### 8.2.2.10 Undervoltage Lockout Setpoint

The system undervoltage lockout (UVLO) is adjusted using the external voltage divider network of  $R_{ENT}$  and  $R_{ENB}$ . The UVLO has two thresholds, one for power up when the input voltage is rising and one for power down or brownouts when the input voltage is falling. The following equation can be used to determine the  $V_{IN}$  UVLO level.

$$V_{IN\_RISING} = V_{ENH} \times \frac{R_{ENT} + R_{ENB}}{R_{ENB}} \quad (19)$$

The EN rising threshold ( $V_{\text{ENH}}$ ) for LMR23610 is set to be 1.55 V (typical). Choose the value of  $R_{\text{ENB}}$  to be 287 k $\Omega$  to minimize input current from the supply. If the desired  $V_{\text{IN}}$  UVLO level is at 6 V, then the value of  $R_{\text{ENT}}$  can be calculated using the equation below:

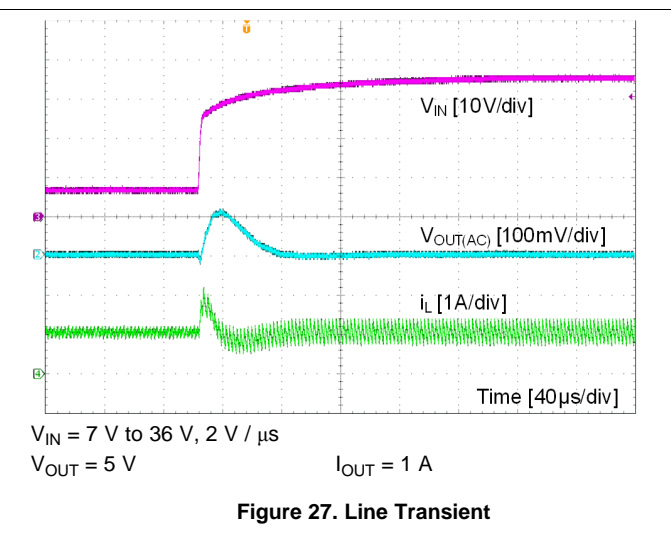
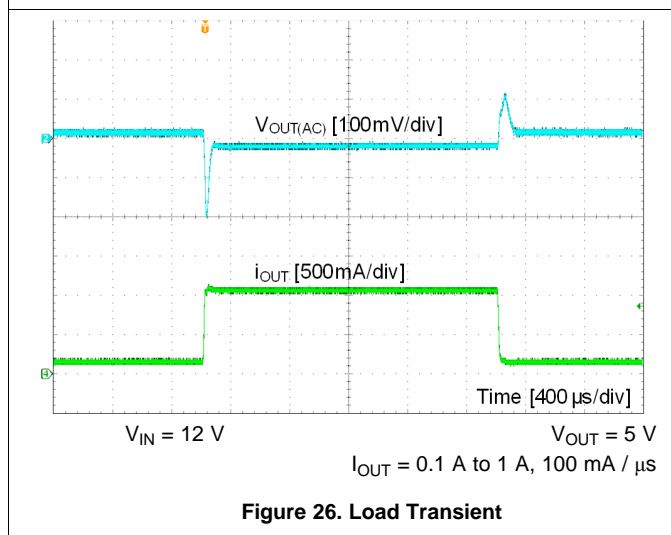
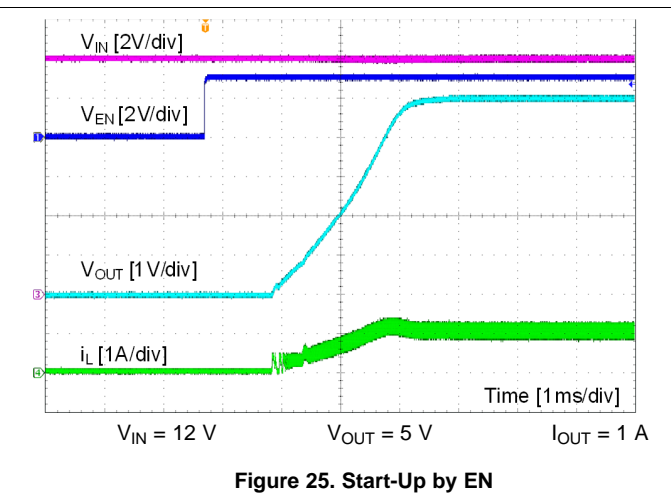
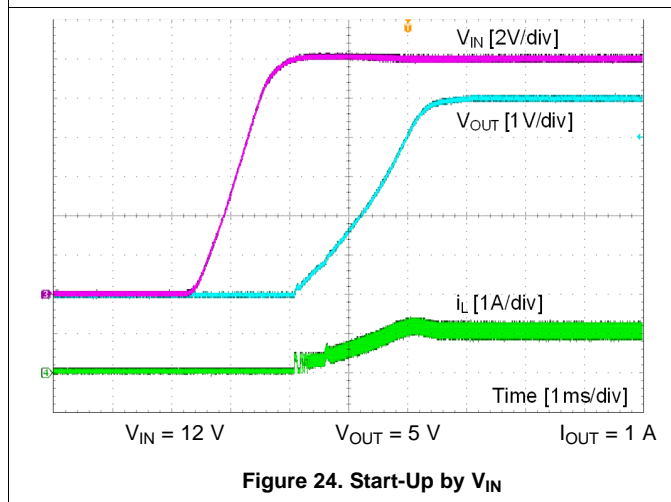
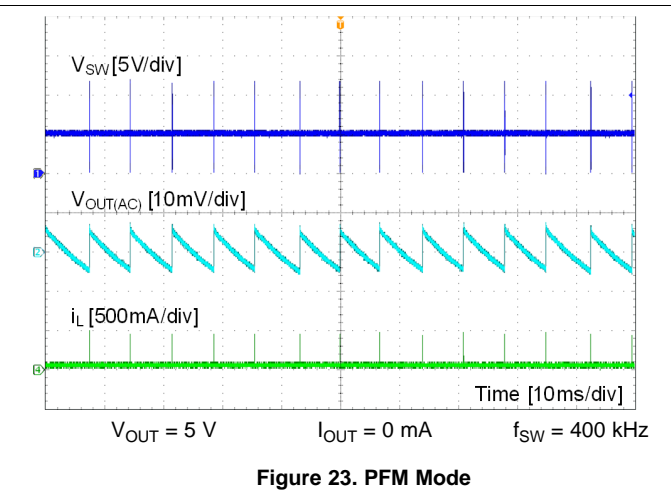
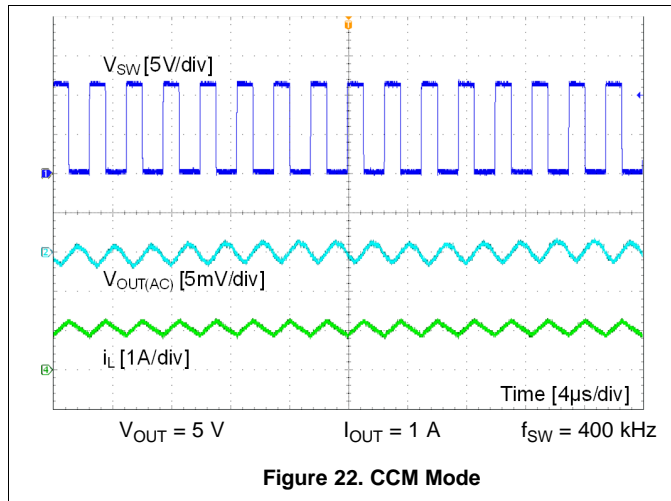
$$R_{\text{ENT}} = \left( \frac{V_{\text{IN\_RISING}}}{V_{\text{ENH}}} - 1 \right) \times R_{\text{ENB}} \quad (20)$$

The above equation yields a value of 820 k $\Omega$ . The resulting falling UVLO threshold, equals 4.4 V, can be calculated by below equation, where EN hysteresis ( $V_{\text{EN\_HYS}}$ ) is 0.4 V (typical).

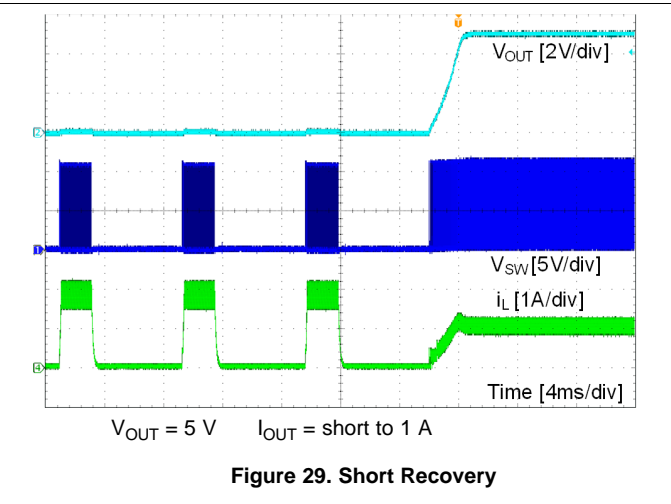
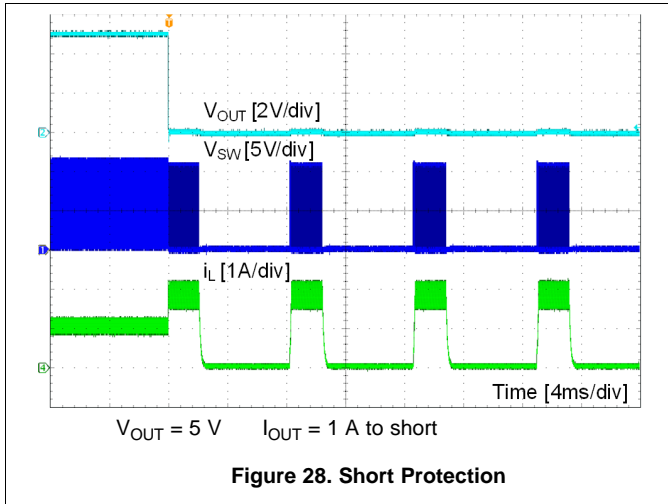
$$V_{\text{IN\_FALLING}} = (V_{\text{ENH}} - V_{\text{EN\_HYS}}) \times \frac{R_{\text{ENT}} + R_{\text{ENB}}}{R_{\text{ENB}}} \quad (21)$$

### 8.2.3 Application Curves

Unless otherwise specified the following conditions apply:  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ ,  $L = 22\text{ }\mu\text{H}$ ,  $C_{OUT} = 47\text{ }\mu\text{F} \times 2$ ,  $T_A = 25^\circ\text{C}$ .



Unless otherwise specified the following conditions apply:  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ ,  $L = 22\text{ }\mu\text{H}$ ,  $C_{OUT} = 47\text{ }\mu\text{F} \times 2$ ,  $T_A = 25^\circ\text{C}$ .



## 9 Power Supply Recommendations

The LMR23610 is designed to operate from an input voltage supply range between 4 V and 36 V. This input supply must be able to withstand the maximum input current and maintain a stable voltage. The resistance of the input supply rail should be low enough that an input current transient does not cause a high enough drop at the LMR23610 supply voltage that can cause a false UVLO fault triggering and system reset. If the input supply is located more than a few inches from the LMR23610, additional bulk capacitance may be required in addition to the ceramic input capacitors. The amount of bulk capacitance is not critical, but a 47- $\mu$ F or 100- $\mu$ F electrolytic capacitor is a typical choice.

## 10 Layout

### 10.1 Layout Guidelines

Layout is a critical portion of good power supply design. The following guidelines will help users design a PCB with the best power conversion performance, thermal performance, and minimized generation of unwanted EMI.

1. The input bypass capacitor  $C_{IN}$  must be placed as close as possible to the VIN and PGND pins. Grounding for both the input and output capacitors should consist of localized top side planes that connect to the PGND pin and PAD.
2. Place bypass capacitors for  $V_{CC}$  close to the VCC pin and ground the bypass capacitor to device ground.
3. Minimize trace length to the FB pin net. Both feedback resistors,  $R_{FBT}$  and  $R_{FBB}$  should be located close to the FB pin. Place  $C_{FF}$  directly in parallel with  $R_{FBT}$ . If  $V_{OUT}$  accuracy at the load is important, make sure  $V_{OUT}$  sense is made at the load. Route  $V_{OUT}$  sense path away from noisy nodes and preferably through a layer on the other side of a shielded layer.
4. Use ground plane in one of the middle layers as noise shielding and heat dissipation path.
5. Have a single point ground connection to the plane. The ground connections for the feedback and enable components should be routed to the ground plane. This prevents any switched or load currents from flowing in the analog ground traces. If not properly handled, poor grounding can result in degraded load regulation or erratic output voltage ripple behavior.
6. Make  $V_{IN}$ ,  $V_{OUT}$  and ground bus connections as wide as possible. This reduces any voltage drops on the input or output paths of the converter and maximizes efficiency.
7. Provide adequate device heat-sinking. Use an array of heat-sinking vias to connect the exposed pad to the ground plane on the bottom PCB layer. If the PCB has multiple copper layers, these thermal vias can also be connected to inner layer heat-spreading ground planes. Ensure enough copper area is used for heat-sinking to keep the junction temperature below 125°C.

#### 10.1.1 Compact Layout for EMI Reduction

Radiated EMI is generated by the high di/dt components in pulsing currents in switching converters. The larger area covered by the path of a pulsing current, the more EMI is generated. High frequency ceramic bypass capacitors at the input side provide primary path for the high di/dt components of the pulsing current. Placing ceramic bypass capacitor(s) as close as possible to the VIN and PGND pins is the key to EMI reduction.

The SW pin connecting to the inductor should be as short as possible, and just wide enough to carry the load current without excessive heating. Short, thick traces or copper pours (shapes) should be used for high current conduction path to minimize parasitic resistance. The output capacitors should be placed close to the  $V_{OUT}$  end of the inductor and closely grounded to PGND pin and exposed PAD.

The bypass capacitors on VCC should be placed as close as possible to the pin and closely grounded to PGND and the exposed PAD.



## Layout Guidelines (continued)

### 10.1.2 Ground Plane and Thermal Considerations

It is recommended to use one of the middle layers as a solid ground plane. Ground plane provides shielding for sensitive circuits and traces. It also provides a quiet reference potential for the control circuitry. The AGND and PGND pins should be connected to the ground plane using vias right next to the bypass capacitors. PGND pin is connected to the source of the internal LS switch. They should be connected directly to the grounds of the input and output capacitors. The PGND net contains noise at switching frequency and may bounce due to load variations. PGND trace, as well as VIN and SW traces, should be constrained to one side of the ground plane. The other side of the ground plane contains much less noise and should be used for sensitive routes.

It is recommended to provide adequate device heat sinking by utilizing the PAD of the IC as the primary thermal path. Use a minimum 4 by 2 array of 12 mil thermal vias to connect the PAD to the system ground plane heat sink. The vias should be evenly distributed under the PAD. Use as much copper as possible, for system ground plane, on the top and bottom layers for the best heat dissipation. Use a four-layer board with the copper thickness for the four layers, starting from the top of, 2 oz / 1 oz / 1 oz / 2 oz. Four layer boards with enough copper thickness provides low current conduction impedance, proper shielding and lower thermal resistance.

The thermal characteristics of the LMR23610 are specified using the parameter  $R_{\theta JA}$ , which characterize the junction temperature of silicon to the ambient temperature in a specific system. Although the value of  $R_{\theta JA}$  is dependent on many variables, it still can be used to approximate the operating junction temperature of the device. To obtain an estimate of the device junction temperature, one may use the following relationship:

$$T_J = P_D \times R_{\theta JA} + T_A$$

where

- $T_J$  = Junction temperature in °C
  - $P_D = V_{IN} \times I_{IN} \times (1 - \text{Efficiency}) - 1.1 \times I_{OUT}^2 \times \text{DCR}$  in Watt
  - DCR = Inductor DC parasitic resistance in  $\Omega$
  - $R_{\theta JA}$  = Junction to ambient thermal resistance of the device in °C/W
  - $T_A$  = Ambient temperature in °C
- (22)

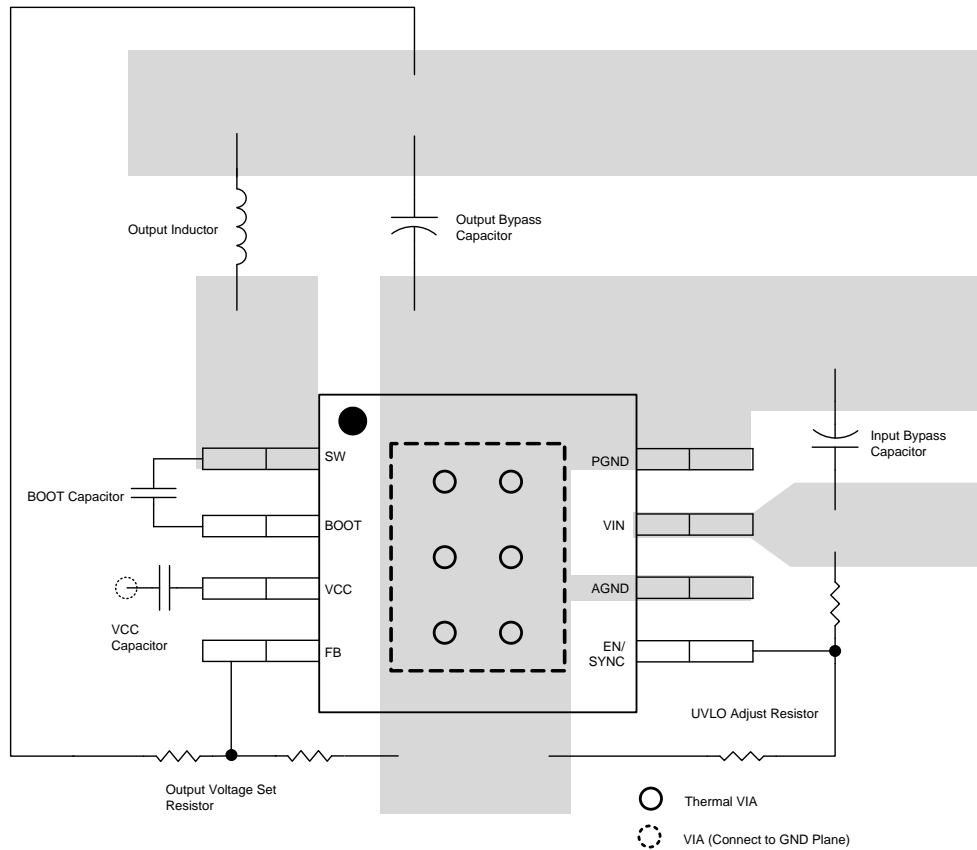
The maximum operating junction temperature of the LMR23610 is 125°C.  $R_{\theta JA}$  is highly related to PCB size and layout, as well as environmental factors such as heat sinking and air flow.

### 10.1.3 Feedback Resistors

To reduce noise sensitivity of the output voltage feedback path, it is important to place the resistor divider and  $C_{FF}$  close to the FB pin, rather than close to the load. The FB pin is the input to the error amplifier, so it is a high impedance node and very sensitive to noise. Placing the resistor divider and  $C_{FF}$  closer to the FB pin reduces the trace length of FB signal and reduces noise coupling. The output node is a low impedance node, so the trace from  $V_{OUT}$  to the resistor divider can be long if short path is not available.

If voltage accuracy at the load is important, make sure voltage sense is made at the load. Doing so will correct for voltage drops along the traces and provide the best output accuracy. The voltage sense trace from the load to the feedback resistor divider should be routed away from the SW node path and the inductor to avoid contaminating the feedback signal with switch noise, while also minimizing the trace length. This is most important when high value resistors are used to set the output voltage. It is recommended to route the voltage sense trace and place the resistor divider on a different layer than the inductor and SW node path, such that there is a ground plane in between the feedback trace and inductor/SW node polygon. This provides further shielding for the voltage feedback path from EMI noises.

**10.2 Layout Example**



**Figure 30. LMR23610 Layout**

## 11 デバイスおよびドキュメントのサポート

### 11.1 WEBENCH®ツールによるカスタム設計

[ここをクリック](#)すると、WEBENCH® Power Designerにより、LMR23610を使用するカスタム設計を作成できます。

1. 最初に、入力電圧( $V_{IN}$ )、出力電圧( $V_{OUT}$ )、出力電流( $I_{OUT}$ )の要件を入力します。
2. オプティマイザのダイヤルを使用して、効率、占有面積、コストなどの主要なパラメータについて設計を最適化します。
3. 生成された設計を、テキサス・インスツルメンツが提供する他のソリューションと比較します。

WEBENCH Power Designerでは、カスタマイズされた回路図と部品リストを、リアルタイムの価格と部品の在庫情報と併せて参照できます。

ほとんどの場合、次の操作を実行可能です。

- 電氣的なシミュレーションを実行し、重要な波形と回路の性能を確認する。
- 熱シミュレーションを実行し、基板の熱特性を把握する。
- カスタマイズされた回路図やレイアウトを、一般的なCADフォーマットでエクスポートする。
- 設計のレポートをPDFで印刷し、同僚と設計を共有する。

WEBENCHツールの詳細は、[www.ti.com/WEBENCH](http://www.ti.com/WEBENCH)でご覧になれます。

### 11.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](http://ti.com)のデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 11.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™オンライン・コミュニティ** *TIのE2E (Engineer-to-Engineer) コミュニティ*。エンジニア間の共同作業を促進するために開設されたものです。e2e.ti.comでは、他のエンジニアに質問し、知識を共有し、アイデアを検討して、問題解決に役立てることが出来ます。

**設計サポート** *TIの設計サポート* 役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。

### 11.4 商標

PowerPAD, E2E are trademarks of Texas Instruments.

WEBENCH, SIMPLE SWITCHER are registered trademarks of Texas Instruments.

All other trademarks are the property of their respective owners.

### 11.5 静電気放電に関する注意事項



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### 11.6 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMR23610ADDA	ACTIVE	SO PowerPAD	DDA	8	75	RoHS & Green	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	F10A	<a href="#">Samples</a>
LMR23610ADDAR	ACTIVE	SO PowerPAD	DDA	8	2500	RoHS & Green	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	F10A	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF LMR23610 :**

- Automotive : [LMR23610-Q1](#)

## NOTE: Qualified Version Definitions:

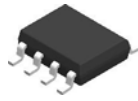
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LMR23610ADDA	DDA	HSOIC	8	75	517	7.87	635	4.25
LMR23610ADDA	DDA	HSOIC	8	75	507	8	3940	4.32

# DDA0008B



# PACKAGE OUTLINE

## PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



4214849/A 08/2016

### NOTES:

PowerPAD is a trademark of Texas Instruments.

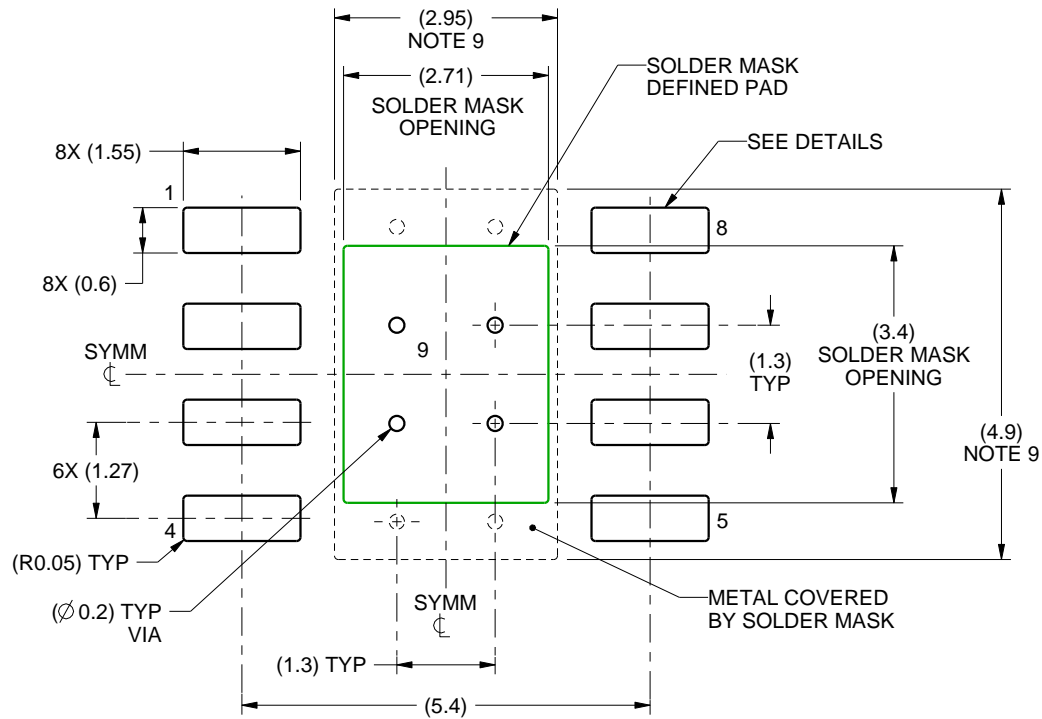
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MS-012.

# EXAMPLE BOARD LAYOUT

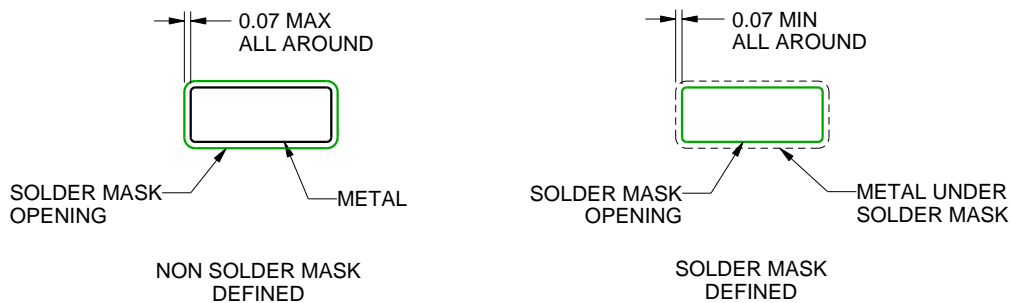
DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
PADS 1-8

4214849/A 08/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 ([www.ti.com/lit/slma002](http://www.ti.com/lit/slma002)) and SLMA004 ([www.ti.com/lit/slma004](http://www.ti.com/lit/slma004)).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



# EXAMPLE STENCIL DESIGN

DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
EXPOSED PAD  
100% PRINTED SOLDER COVERAGE BY AREA  
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.03 X 3.80
0.125	2.71 X 3.40 (SHOWN)
0.150	2.47 X 3.10
0.175	2.29 X 2.87

4214849/A 08/2016

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL-OUTLINE



4202561/F 12/11

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion not to exceed 0,15.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.

DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE

## THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206322-6/L 05/12

NOTE: A. All linear dimensions are in millimeters

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- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
  - F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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